2SK2431

Silicon N-Channel MOS FET

HITACHI

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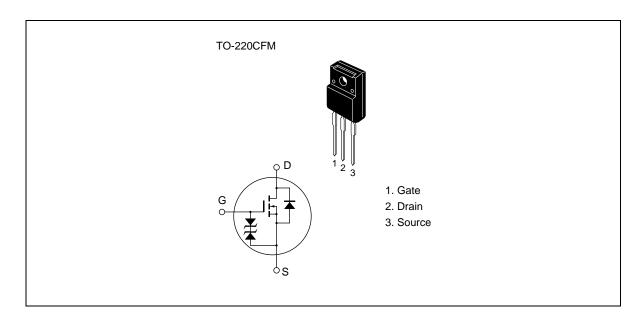
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No Secondary Breakdown
- Suitable for Switching regulator, DC-DC converter.

Outline



2SK2431

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	450	V
Gate to source voltage	V _{gss}	±30	V
Drain current	I _D	3	A
Drain peak current	h ^{*1} D(pulse)	12	A
Body to drain diode reverse drain current	I _{DR}	3	A
Channel dissipation	Pch*2	25	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes 1. PW \leq 10 μ s, duty cycle \leq 1 %

2. Value at Tc = 25 $^{\circ}$ C

Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	450	_	_	V	$I_{D} = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±30	_	_	V	$I_{_G} = \pm 100 \ \mu A, \ V_{_{DS}} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	250	μΑ	$V_{DS} = 450 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{\text{GS(off)}}$	2.0	_	3.0	V	$I_{D} = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{\scriptscriptstyle DS(on)}$	_	2.0	2.8	Ω	$I_{D} = 2 A$ $V_{GS} = 10 V^{*1}$
Forward transfer admittance	y _{fs}	1.5	2.5	_	S	$I_{D} = 2 A$ $V_{DS} = 10 V^{*1}$
Input capacitance	Ciss	_	330	_	pF	$V_{DS} = 10 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	Coss	_	90	_	pF	_
Reverse transfer capacitance	Crss	_	15	_	pF	_
Turn-on delay time	$\mathbf{t}_{\text{d(on)}}$	_	7	_	ns	$I_{D} = 2 A$ $V_{GS} = 10 V$ $R_{L} = 15\Omega$
Rise time	t _r	_	20	_	ns	_
Turn-off delay time	$\mathbf{t}_{d(off)}$		30		ns	_
Fall time	t _f	_	20	_	ns	
Body to drain diode forward voltage	V_{DF}		0.9	_	V	$I_{\rm F} = 3 \text{ A}, V_{\rm GS} = 0$
Body to drain diode reverse recovery time	t _{rr}	_	300	_	ns	$I_F = 3 \text{ A}, V_{GS} = 0,$ diF / dt = 100 A / μ s
Note 4 Dules Test						

Note 1. Pulse Test

See characteristics curves of 2SK1153, 2SK1862.

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